Advanced Micro Devices

PAL16R8 Family

20-Pin TTL Programmable Array Logic

DISTINCTIVE CHARACTERISTICS

- As fast as 4.5 ns maximum propagation delay
- Popular 20-pin architectures: 16L8, 16R8, 16R6, 16R4
- Programmable replacement for high-speed TTL logic
- Register preload for testability

- Power-up reset for initialization
- Extensive third-party software and programmer support through FusionPLD partners
- 20-Pin DIP and PLCC packages save space
- 28-Pin PLCC-4 package provides ultra-clean high-speed signals

GENERAL DESCRIPTION

The PAL16R8 Family (PAL16L8, PAL16R8, PAL16R6, PAL16R4) includes the PAL16R8-5/4 Series which provides the highest speed in the 20-pin TTL PAL device family, making the series ideal for high-performance applications. The PAL16R8 Family is provided with standard 20-pin DIP and PLCC pinouts and a 28-pin PLCC pinout. The 28-pin PLCC pinout contains seven extra ground pins interleaved between the outputs to reduce noise and increase speed.

The devices provide user-programmable logic for replacing conventional SSI/MSI gates and flip-flops at a reduced chip count.

The family allows the systems engineer to implement the design on-chip, by opening fuse links to configure AND and OR gates within the device, according to the desired logic function. Complex interconnections between gates, which previously required time-consuming layout, are lifted from the PC board and placed on silicon, where they can be easily modified during prototyping or production.

The PAL device implements the familiar Boolean logic transfer function, the sum of products. The PAL device is a programmable AND array driving a fixed OR array.

The AND array is programmed to create custom product terms, while the OR array sums selected terms at the outputs.

In addition, the PAL device provides the following options:

- Variable input/output pin ratio
- Programmable three-state outputs
- Registers with feedback

Product terms with all connections opened assume the logical HIGH state; product terms connected to both true and complement of any single input assume the logical LOW state. Registers consist of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock. Unused input pins should be tied to Vcc or GND.

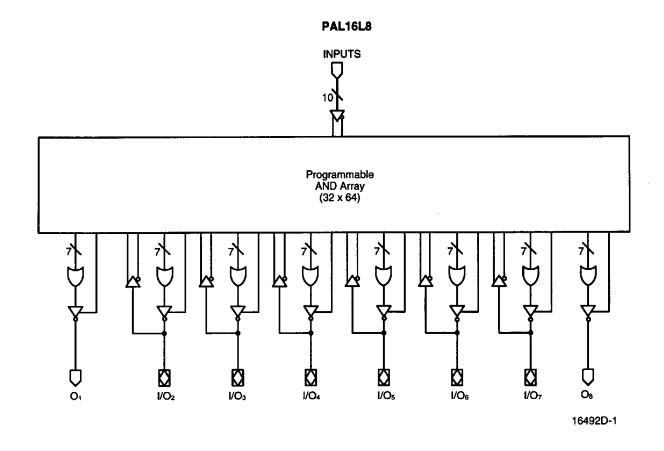
The entire PAL device family is supported by the FusionPLD partners. The PAL family is programmed on conventional PAL device programmers with appropriate personality and socket adapter modules. Once the PAL device is programmed and verified, an additional connection may be opened to prevent pattern readout. This feature secures proprietary circuits.

PRODUCT SELECTOR GUIDE

Device	Dedicated Inputs	Outputs	Product Terms/ Output	Feedback	Enable
PAL16L8	10	6 comb. 2 comb.	7 7	I/O -	prog. prog.
PAL16R8	8	8 reg.	8	reg.	pin
PAL16R6	8	6 reg. 2 comb.	8 7	reg. I/O	pin prog.
PAL16R4	8	4 reg. 4 comb.	8 7	reg. I/O	pin prog.

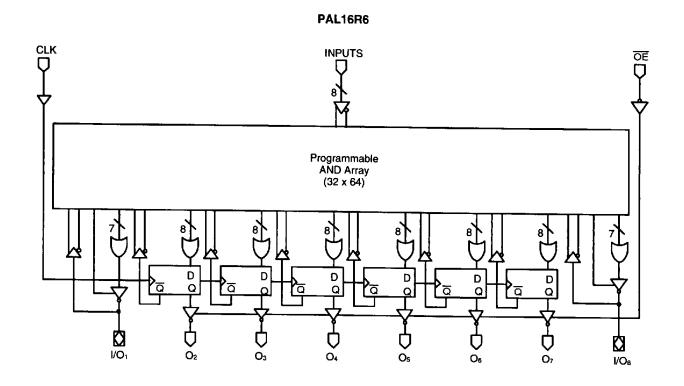
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BLOCK DIAGRAMS

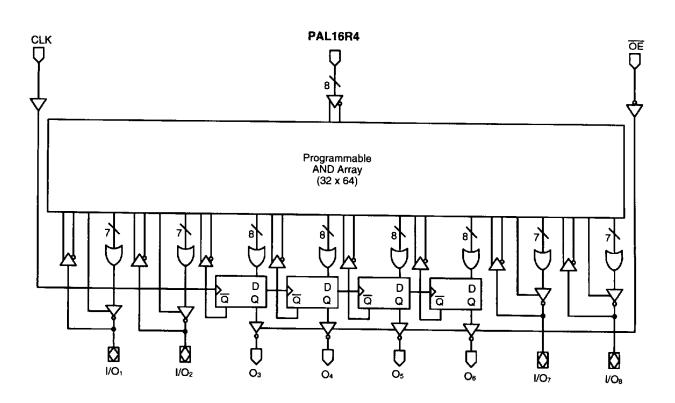


Programmable AND Array (32 x 64) Programmable AND Array (32 x 64) 16492D-2

BLOCK DIAGRAMS



16492D-3



16492D-4

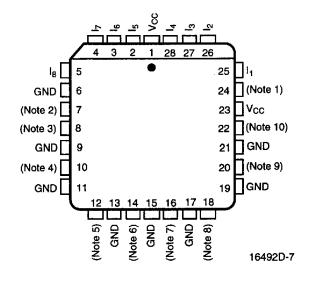
CONNECTION DIAGRAMS

Top View

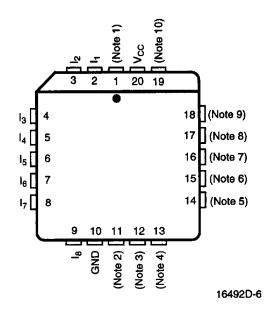
DIP 20 Vcc (Note 1) L 19 (Note 10) lı [18 (Note 9) 12 17 (Note 8) 13 16 ☐ (Note 7) 14 ☐ (Note 6) 15 L 15 14 (Note 5) 16 (Note 4) 13 17 L (Note 3) l8 12 (Note 2) GND

28-Pin PLCC

16492D-5



20-Pin PLCC



PIN DESIGNATIONS

CLK Clock **GND** Ground Input 1/0 Input/Output Output 0

Œ **Output Enable** Vcc Supply Voltage

Note:

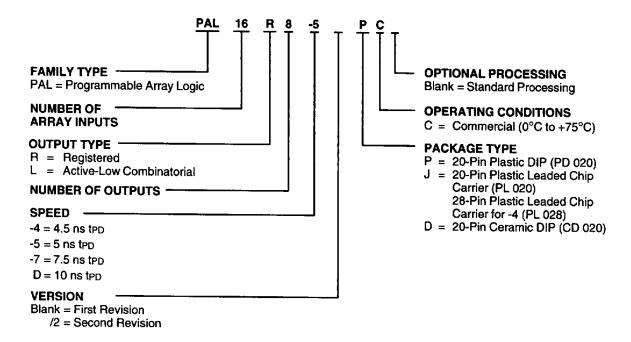
Pin 1 is marked for orientation.

Note	16L8	16R8	16R6	16R4
1	l ₀	CLK	CLK	CLK
2	lg	ŌĒ .	ŌĒ	ŌĒ
3	O ₁	O ₁	I/O ₁	I/O ₁
4	I/O ₂	O ₂	O ₂	I/O ₂
5	I/O ₃	O ₃	Оз	O₃
6	I/O ₄	O ₄	O ₄	O ₄
7	I/O ₅	O ₅	O ₅	O ₅
8	I/O ₆	O ₆	O ₆	O ₆
9	I/O ₇	O ₇	O ₇	I/O ₇
10	O ₈	Ов	I/O ₈	I/O ₈



ORDERING INFORMATION Commercial Products

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid	Combinations
PAL16L8	
PAL16R8	5DC 510 410
PAL16R6	-5PC, -5JC, -4JC
PAL16R4	
PAL16L8-7	
PAL16R8-7	PC, JC, DC
PAL16R6-7	. 0, 00, 50
PAL16R4-7	
PAL16L8D/2	
PAL16R8D/2	PC, JC
PAL16R6D/2	, 5, 60
PAL16R4D/2	

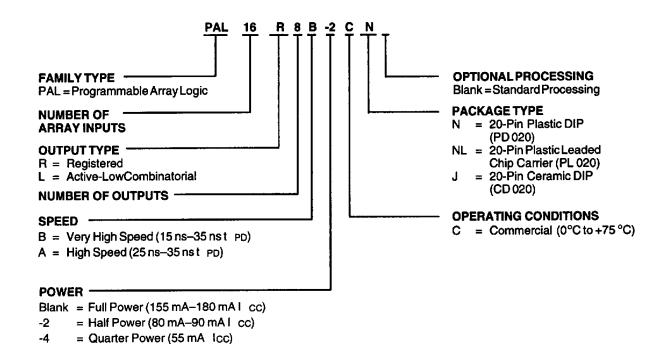
Valid Combinations

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

ORDERINGINFORMATION

Commercial Products (MMI Marking Only)

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations							
PAL16L8							
PAL16R8	B B-2 A	ON ON					
PAL16R6	B, B-2, A, B-4	CN, CNL, CJ					
PAL16R4							

Valid Combinations

ValidCombinationslists configurationsplanned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly releasedcombinations.

Note: Marked with MMI logo.

FUNCTIONAL DESCRIPTION

Standard 20-Pin PAL Family

The standard bipolar 20-pin PAL family devices have common electrical characteristics and programming procedures. Four different devices are available, including both registered and combinatorial devices. All parts are produced with a fuse link at each input to the AND gate array, and connections may be selectively removed by applying appropriate voltages to the circuit. Utilizing an easily-implemented programming algorithm, these products can be rapidly programmed to any customized pattern. Extra test words are preprogrammed during manufacturing to ensure extremely high field programming yields, and provide extra test paths to achieve excellent parametric correlation.

Pinouts

The PAL16R8 Family is available in the standard 20-pin DIP and PLCC pinouts and the PAL16R8-4 Series is available in the new 28-pin PLCC pinout. The 28-pin PLCC pinout gives the designer the cleanest possible signal with only 4.5 ns delay.

The PAL16R8-4 pinout has been designed to minimize the noise that can be generated by high-speed signals. Because of its inherently shorter leads, the PLCC package is the best package for use in high-speed designs. The short leads and multiple ground signals reduce the effective lead inductance, minimizing ground bounce. Placing the ground pins between the outputs optimizes the ground bounce protection, and also isolates the outputs from each other, eliminating cross-talk. This pinout can reduce the effective propagation delay by as much as 20% from a standard DIP pinout. Design files for PAL16R8-4 Series devices are written as if the device had a standard 20-pin DIP pinout for most design software packages.

Variable Input/Output Pin Ratio

The registered devices have eight dedicated input lines, and each combinatorial output is an I/O pin. The PAL16L8 has ten dedicated input lines and six of the eight combinatorial outputs are I/O pins. Buffers for device inputs have complementary outputs to provide user-programmable input signal polarity. Unused input pins should be tied to Vcc or GND.

Programmable Three-State Outputs

Each output has a three-state output buffer with three-state control. On combinatorial outputs, a product term controls the buffer, allowing enable and disable to be a function of any product of device inputs or output feedback. The combinatorial output provides a bidirectional I/O pin and may be configured as a dedicated input if the output buffer is always disabled. On registered outputs, an input pin controls the enabling of the three-state outputs.

Registers with Feedback

Registered outputs are provided for data storage and synchronization. Registers are composed of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock input.

Register Preload

The register on the AMD marked 16R8, 16R6, and 16R4 devices can be preloaded from the output pins to facilitate functional testing of complex state machine designs. This feature allows direct loading of arbitrary states, making it unnecessary to cycle through long test vector sequences to reach a desired state. In addition, transitions from illegal states can be verified by loading illegal states and observing proper recovery.

Power-Up Reset

All flip-flops power-up to a logic LOW for predictable system initialization. Outputs of the PAL16R8 Family will be HIGH due to the active-low outputs. The Vcc rise must be monotonic and the reset delay time is 1000 ns maximum.

Security Fuse

After programming and verification, a PAL16R8 Family design can be secured by programming the security fuse. Once programmed, this fuse defeats readback of the internal programmed pattern by a device programmer, securing proprietary designs from competitors. When the security fuse is programmed, the array will read as if every fuse is programmed.

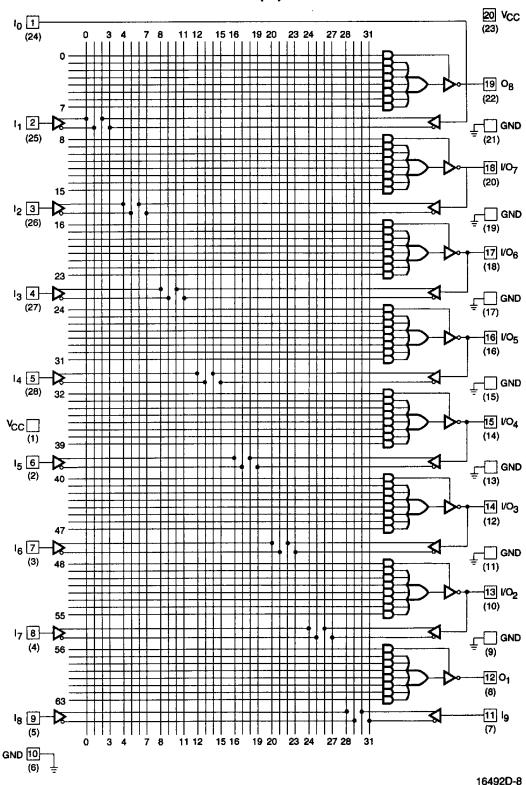
Quality and Testability

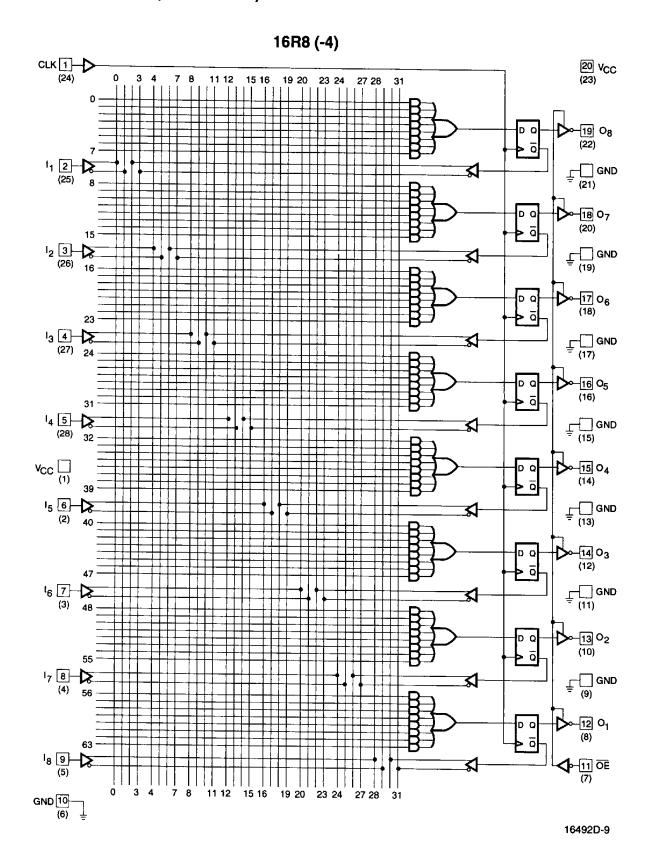
The PAL16R8 Family offers a very high level of built-in quality. Extra programmable fuses provide a means of verifying performance of all AC and DC parameters. In addition, this verifies complete programmability and functionality of the device to provide the highest programming yields and post-programming functional yields in the industry.

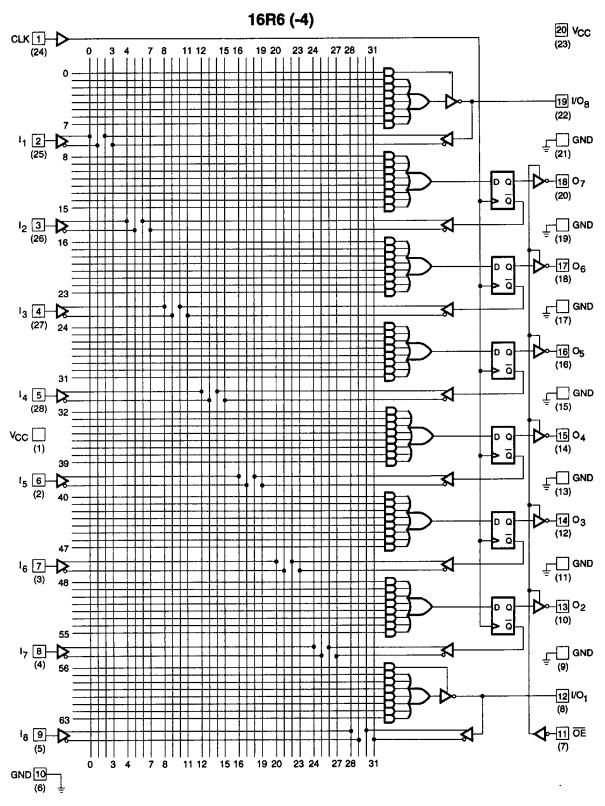
Technology

The PAL16R8-5, -7 and D/2 are fabricated with AMD's oxide isolated bipolar process. The array connections are formed with highly reliable PtSi fuses. The PAL16R8B, B-2, A and B-4 series are fabricated with AMD's advanced trench-isolated bipolar process. The array connections are formed with proven TiW fuses for reliable operation. These processes reduce parasitic capacitances and minimum geometries to provide higher performance.



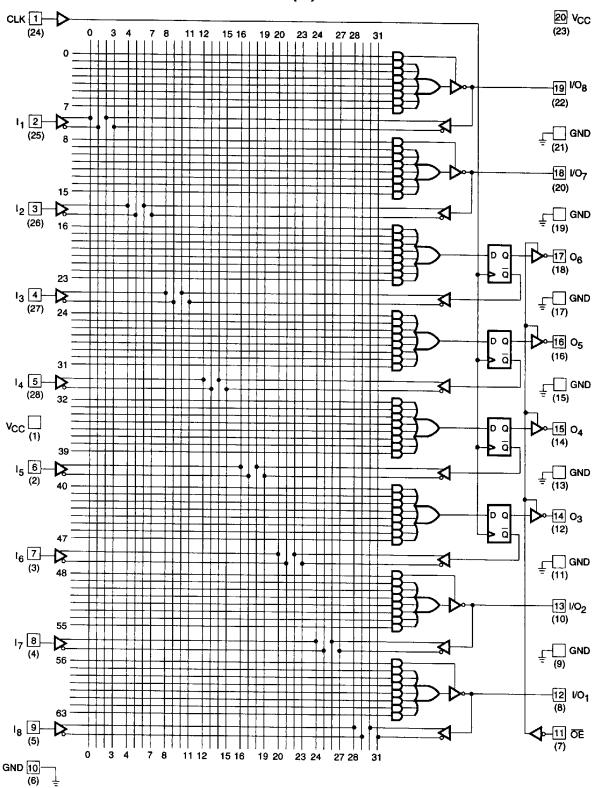






16492D-10

16R4 (-4)



16492D-11



Ambient Temperature with Power Applied -65°C to +150°C Storage Temperature -55°C to +125°C Supply Voltage with Respect to Ground -0.5 V to + 7.0 V DC Input Voltage -1.2 V to Vcc + 0.5 V DC Output or I/O Pin Voltage -0.5 V to Vcc + 0.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Static Discharge Voltage 2001 V

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A) Operating in Free Air 0°C to +75°C Supply Voltage (Vcc) with Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = -3.2 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min	2.4		٧
Vol	Output LOW Voltage	I _{OL} = 24 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VıL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vi	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min		-1.2	٧
lıн	Input HIGH Current	V _{IN} = 2.7 V, V _∞ = Max (Note 2)		25	μА
l _{IL}	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 2)		-250	μА
lı .	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max		1	mA
lozн	Off-State Output Leakage Current HIGH	V _{OUT} = 2.7 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μΑ
lozu	Off-State Output Leakage Current LOW	V _{OUT} = 0.4 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		-100	μА
Isc	Output Short-Circuit Current	V _{OUT} = 0.5 V, V _{CC} = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lour = 0 mA) V _{CC} = Max		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of I_{IL} and lozL (or I_IH and lozH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vou τ = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description		Test Condition	ns	Typ	Unit
Cin	Input Capacitance	CLK, OE	VIN = 2.0 V	Vcc = 5.0 V	8	
	 	I ₁ I ₈		T _A = 25°C	5	pF
Соит	Output Capacitance)	Vout = 2.0 V	f = 1 MHz	8	"

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

					-5		-4		
Parameter Symbol	Parameter D	escription			Min (Note 3)	Max	Min (Note 3)	Max	Unit
t _{PD}	Input or Feed	back to Combinatorial	eack to Combinatorial Output		1	5	1	4.5	ns
ts	Setup Time fr	om Input or Feedback	to Clock		4.5		4.5		ns
tн	Hold Time				0		0		ns
too	Clock to Outp	out			1	4.0	1	3.5	ns
tskewa	Skew Betwee	n Registered Outputs (Note 4)		1		1		0.5	ns
twL	2 1	bck Width HIGH		16R8, 16R6, 16R4	4		4		ns
twн	Clock Width			1004	4	-	4		ns
	Maximum	External Feedback	1/(ts + tco)	1	117		125		MHz
fmax	Frequency (Note 5)	Internal Feedback (fcnt)	1/(ts + tcr) (Note 6)		125		125		MHz
		No Feedback	1/(twn + twL)	1	125		125		MHz
tezx	OE to Output	Enable		1	1	6.5	1	6.5	ns
texz	OE to Output	Disable		1	1		1	5	ns
tea	Input to Output Product Term	o Output Enable Using		4610 4600	2	6.5	2	6.5	ns
ten	Input to Output Disable Using Product Term Control		16L8, 16R6, 16R4	2	5	2	5	ns	

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums for tpd, tco, tpzx, tpxz, teA, and teR are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. Skew testing takes into account pattern and switching direction differences between outputs.
- 5. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.
- 6. t_{CF} is a calculated value and is not guaranteed. t_{CF} can be found using the following equation: $t_{CF} = 1/f_{MAX}$ (internal feedback) t_{S} .

^{1.} These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with
Power Applied -55°C to +125°C

Supply Voltage with
Respect to Ground -0.5 V to + 7.0 V

DC Input Voltage -1.2 V to + 7.0 V

DC Input Current -30 mA to + 5 mA

DC Output or I/O Pin

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Voltage -0.5 V to Vcc + 0.5 V Static Discharge Voltage 2001 V

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)
Operating in Free Air 0°C to +75°C
Supply Voltage (Vcc)
with Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
V _{ОН}	Output HIGH Voltage	$I_{OH} = -3.2 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		>
Vol	Output LOW Voltage	IoL = 24 mA VIN = VIH or VIL Vcc = Min		0.5	V
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vi	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min		-1.2	٧
l _{IH}	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max (Note 2)		25	μΑ
lıL	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 2)		-250	μΑ
1,	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max		1	mA
lozн	Off-State Output Leakage Current HIGH	V _{OUT} = 2.7 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	V _{OUT} = 0.4 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		-100	μА
Isc	Output Short-Circuit Current	V _{оит} = 0.5 V, V _{сс} = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) V _{CC} = Max		180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of I_{IL} and IOZL (or I_{IH} and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	V _{IN} = 2.0 V	Vcc = 5.0 V	5	
Соит	Output Capacitance	Vоит = 2.0 V	Vcc = 5.0 V T _A = 25°C f = 1 MHz	8	pF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	Min (Note 3)	Max	Unit			
t _{PD}	Input or Feedba			16L8, 16R6,	3	7.5	
(10)	Combinatorial C	Output 1	Output Switching	16R4	3	7	лѕ
ts	Setup Time from	n Input or Feedback to	Clock		7		ns
tн	Hold Time			1	0		ns
tco	Clock to Output			7	1	6.5	ns
tskew	Skew Between	Registered Outputs (N	ote 4)	16R8, 16R6,			ns
twL	Clock Width	LOW		16R4	5		ns
twн		HIGH		1	5		ns
	Maximum	External Feedback	1/(ts + tco)]	74		MHz
fmax	Frequency (Note 5)	Internal Feedback (fcnt)	1/(ts + tcF) (Note 6)		100		MHz
		No Feedback	1/(twn + twL)		100		MHz
tezx	OE to Output Er	nable		1	1	8	ns
t _{PXZ}	OE to Output Di	OE to Output Disable		1	1	8	ns
tea	Input to Output	Input to Output Enable Using Product Term Control		16L8, 16R6,	3	10	ns
ten	Input to Output I	Disable Using Product	Term Control	16R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums for t_{PD}, t_{CO}, t_{PZX}, t_{PXZ}, t_{EA}, and t_{ER} are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- Skew is measured with all outputs switching in the same direction.
- 5. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.
- 6. t_{CF} is a calculated value and is not guaranteed. t_{CF} can be found using the following equation: $t_{CF} = 1/f_{MAX}$ (internal feedback) t_{S} .

^{1.} These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to + 7.0 V

DC Input Voltage -1.5 V to + 5.5 V

DC Output or I/O Pin Voltage -0.5 V to + 5.5 V

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Static Discharge Voltage 2001 V

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)

Operating in Free Air 0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	I _{OH} = -3.2 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min	2.4		٧
Vol	Output LOW Voltage	I _{OL} = 24 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		8.0	٧
Vı	Input Clamp Voltage	l _{IN} = −18 mA, V _{CC} = Min		-1.5	٧
Іін	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max (Note 2)		25	μΑ
lii.	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 2)		-250	μА
łı	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max		100	μА
Іохн	Off-State Output Leakage Current HIGH	V _{OUT} = 2.4 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	V _{OUT} = 0.4 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μА
Isc	Output Short-Circuit Current	V _{OUT} = 0.5 V, V _{CC} = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) V _{CC} = Max		180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second.
 VOUT = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Condition	18	Тур	Unit
Cin	Input Capacitance	V _{IN} = 2.0 V	V _{CC} = 5.0 V T _A = 25°C	5	
Соит	Output Capacitance	V _{OUT} = 2.0 V	f = 1 MHz	8	рF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Desc	Parameter Description					Unit
teo	Input or Feedbac	ck to Combinatorial Outpu	o Combinatorial Output 16L8, 16R6, 16R4			10	ns
ts	Setup Time from	Input or Feedback to Clo	ck		10		ns
t _H	Hold Time]	0	-	ns
tco	Clock to Output					7	ns
twL	Clock Width	LOW	LOW		8		ns
twн		HIGH		16R8, 16R6,	8		ns
	Maximum Frequency (Note 4)	External Feedback	1/(ts + tco)	16R4	58.8		MHz
f _{MAX}		Internal Feedback (fcnt)	1/(ts + tcr) (Note 5)		60		MHz
		No Feedback	1/(tw+ twL)	1	62.5		MHz
tezx	OE to Output En	able		1	2	10	ns
texz	OE to Output Dis	OE to Output Disable			2	10	ns
tea	Input to Output E	Input to Output Enable Using Product Term Control			3	10	ns
ten	Input to Output D	Disable Using Product Ter	m Control	16R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums for t_{PD}, t_{CO}, t_{PZX}, t_{PXZ}, t_{EA}, and t_{ER} are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.
- 5. t_{CF} is a calculated value and is not guaranteed. t_{CF} can be found using the following equation: $t_{CF} = 1/f_{MAX}$ (internal feedback) t_{S} .

^{1.} These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C Ambient Temperature with Supply Voltage with Respect to Ground -0.5 V to +7.0 V DC Input Voltage −1.5 V to V_{CC} + 0.5 V DC Output or I/O Pin

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Voltage -0.5 V to Vcc + 0.5 V

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A) Operating in Free Air 0°C to +75°C Supply Voltage (Vcc)

Operating ranges define those limits between which the functionality of the device is guaranteed.

with Respect to Ground +4.75 V to +5.25 V

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions		Min	Max	Unit
Vон	Output HIGH Voltage	lон = −3.2 mA	V _{IN} = V _{IH} or V _{IL} V _{CC} = Min	2.4		٧
Vol	Output LOW Voltage	l _{OL} = 24 mA	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$		0.5	٧
ViH	Input HIGH Voltage		Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)			>
ViL	Input LOW Voltage	Guaranteed Input L Voltage for all Input		0.8	٧	
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} =		-1.2	٧	
Іін	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max (Note 2)			25	μA
l _{IL}	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = 1	Max (Note 2)		-250	μА
l _i	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = I	Мах		100	μА
lozн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Vin = Vih or Vil (Not			100	μA
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			-100	μА
lsc	Output Short-Circuit Current	Vout = 0.5 V, Vcc =	Max (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs 0 V _{CC} = Max	Open (lout = 0 mA)		180	mA

- These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	V _{IN} = 2.0 V	Vcc = 5.0 V	8	
Соит	Output Capacitance	V _{OUT} = 2.0 V	T _A = 25°C f = 1 MHz	9	pF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	Parameter Description					Unit
tpo	Input or Feedba	ick to Combinatorial Outpu	k to Combinatorial Output			15	ns
ts	Setup Time from	n Input or Feedback to Clo	Input or Feedback to Clock				ns
tн	Hold Time		1	0		ns	
t∞	Clock to Output	or Feedback	or Feedback			12	ns
twL	Clock Width	LOW		1	10		ns
twн		HIGH		16R8, 16R6, 16R4	10		ns
fmax	Maximum	External Feedback	1/(ts + tco)		37		MHz
IMAX	Frequency (Note 3)	No Feedback	1/(tw+ + twL)		50		MHz
tezx	OE to Output Er	nable		1		15	ns
texz	OE to Output Di	sable				15	ns
tea	Input to Output	put to Output Enable Using Product Term Control				15	ns
ter	Input to Output	Disable Using Product Ter	m Control	16R8,16R6, 16R4		15	ns

- 2. See Switching Test Circuit for test conditions.
- 3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

^{1.} These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature-65°C to +150°C Ambient Temperature with Supply Voltage with Respect to Ground -0.5 V to +7.0 V DC Input Voltage -1.5 V to Vcc + 0.5 V DC Output or I/O Pin

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A) Operating in Free Air 0°C to +75°C Supply Voltage (Vcc) with Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	I _{OH} = -3.2 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min	2.4		٧
Vol	Output LOW Voltage	IoL = 24 mA VIN = VIH or VIL VCC = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min		-1.2	٧
ын	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max (Note 2)		25	μА
In	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 2)		-100	μА
lı	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max		100	μА
lozh	Off-State Output Leakage Current HIGH	V _{OUT} = 2.7 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
loc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) V _{CC} = Max		90	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- I/O pin leakage is the worst case of I_{IL} and I_{QZL} (or I_{IH} and I_{QZH}).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vou⊤ = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
C _{IN}	Input Capacitance	V _{IN} = 2.0 V	Vcc = 5.0 V	7	
Соит	Output Capacitance	V _{OUT} = 2.0 V	T _A = 25°C f = 1 MHz	7	pF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	cription	P	Min	Max	Unit	
teo	Input or Feedba	ck to Combinatorial Outpu	to Combinatorial Output 16L8, 16R6, 16R4			25	ns
ts	Setup Time from	n Input or Feedback to Clo	Input or Feedback to Clock				ns
tн	Hold Time				0		ns
tco	Clock to Output	LOW				15	ns
twL	Clock Width				15		ns
twn		HIGH		16R8, 16R6, 16R4	15		ns
	Maximum	External Feedback	1/(ts + tco)	10/14	25		MHz
f _{MAX}	Frequency (Note 4)	Internal Feedback (fсмт)	1/(ts + tcr) (Note 5)		28.5		MHz
		No Feedback	1/(tw+ + twL)		33		MHz
tezx	OE to Output Er	nable]	20	ns	
texz	OE to Output Di	OE to Output Disable				20	ns
tea	Input to Output I	Input to Output Enable Using Product Term Control				25	ns
ten	Input to Output I	Disable Using Product Ter	rm Control	16R8, 16R6, 16R4		25	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Calculated from measured f_{MAX} internal.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 5. t_{CF} is a calculated value and is not guaranteed. t_{CF} can be found using the following equation: $t_{CF} = 1/f_{MAX}$ (internal feedback) - t_{S} .

^{1.} These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to + 7.0 V DC Input Voltage -1.5 V to Vcc + 0.5 V

DC Output or I/O Pin

Voltage -0.5 V to Vcc + 0.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)
Operating in Free Air 0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Descript	ion	Test Condition	ıs	Min	Max	Unit
Vон	Output HIGH Voltage	,	I _{OH} = -3.2 mA	V _{IN} = V _{IH} or V _{IL} V _{CC} = Min	2.4		٧
Vol	Output LOW Voltage		loL = 24 mA	V _{IN} = V _{IH} or V _{IL} V _{CC} = Min		0.5	٧
ViH	Input HIGH Voltage			Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)			٧
ViL	Input LOW Voltage		Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)			0.8	٧
Vı	Input Clamp Voltage		I _{IN} = -18 mA, V ₀	cc = Min		-1.2	٧
lи	Input HIGH Current	Input HIGH Current		= Max (Note 2)		25	μА
l _{IL}	Input LOW Current		V _{IN} = 0.4 V, V _{CC} = Max (Note 2)			-250	μА
l ₁	Maximum Input Curre	ent	V _{IN} = 5.5 V, V _{CC} = Max			100	μА
Іохн	Off-State Output Leal Current HIGH	kage	V _{OUT} = 2.7 V, V _{OUT} = V _{IH} or V _{IL} (100	μΑ
lozu	Off-State Output Leal Current LOW	kage	Vout = 0.4 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 2)			-100	μА
Isc	Output Short-Circuit (Current	V _{OUT} = 0.5 V, V _{CC} = Max (Note 3)		-30	-130	mA
l∞	Supply Current	16L8 16R8/6/4	V _{IN} = 0 V, Outpu V _{CC} = Max	its Open (loυτ = 0 mA)		155 180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vcc = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	V _{IN} = 2.0 V	Vcc = 5.0 V	7	
Соит	Output Capacitance	Vout = 2.0 V	Ta = 25°C f = 1 MHz	7	pF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	cription		Min	Max	Unit	
t PD	Input or Feedba	ck to Combinatorial Outpo	to Combinatorial Output 16L8, 16R6, 16R4			25	пѕ
ts	Setup Time fron	n Input or Feedback to Clo	Input or Feedback to Clock				ns
tн	Hold Time				0		ns
tco	Clock to Output					15	ns
tw∟	Clock Width	LOW			15		ns
twн		HIGH		┨	15		ns
	Maximum Frequency (Note 4)	External Feedback	1/(ts + tco)	16R8, 16R6, 16R4	25		MHz
f MAX		Internal Feedback (fcnt)	1/(ts + tcF) (Note 5)	1	28.5		MHz
		No Feedback	1/(tw+ + twL)	╡	33		MHz
tezx	OE to Output Er	nable				20	ns
texz	OE to Output Di	sable		7		20	лѕ
tea	Input to Output	Input to Output Enable Using Product Term Control				25	ns
ten	Input to Output	Disable Using Product Te	sable Using Product Term Control			25	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Calculated from measured f_{MAX} internal.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 5. t_{CF} is a calculated value and is not guaranteed. t_{CF} can be found using the following equation: $t_{CF} = 1/f_{MAX}$ (internal feedback) t_{S} .

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C Ambient Temperature with Power Applied -55°C to +125°C Supply Voltage with Respect to Ground -0.5 V to +7.0 V DC Input Voltage -1.5 V to +5.5 V DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)

Operating in Free Air 0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	$I_{OH} = -1 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = Min$	2.4		>
Vol	Output LOW Voltage	$I_{OL} = 8 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = \text{Min}$		0.5	٧
V _{IH}	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		V
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min		-1.5	٧
l _{iH}	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max (Note 2)		25	μΑ
lı∟	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 2)		-250	μΑ
lı	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max		100	μΑ
lozH	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μА
l _{ozL}	Off-State Output Leakage Current LOW	Vout = 0.4 V, V _{CC} = Max V _{IN} = V _{IH} or V _{IL} (Note 2)		-100	μΑ
Isc	Output Short-Circuit Current	V _{OUT} = 0.5 V, V _{CC} = Max (Note 3)	-30	-250	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (I _{OUT} = 0 mA) V _{CC} = Max		55	mA

- These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of I_{IL} and IOZL (or I_IH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V as been chosen to avoid test problems caused by tester ground degradation.

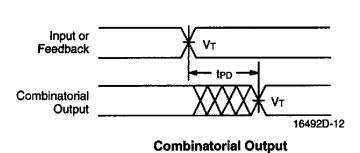


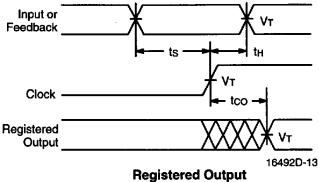
SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)

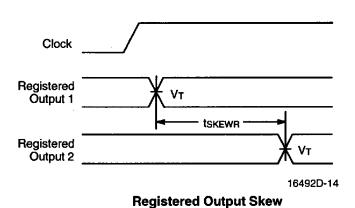
Parameter Symbol	Parameter Des	cription		Min	Max	Unit	
tpp	Input or Feedba	ck to Combinatorial Outpo	ut	16L8, 16R6, 16R4		35	ns
ts	Setup Time from	n Input or Feedback to Clo		35		ns	
t _H	Hold Time]	0		ns	
tco	Clock to Output	or Feedback		16R8, 16R6,		25	ns
tw∟	Clock Width	LOW	LOW		25		ns
twн	<u>]</u>	HIGH		1	25		ns
fmax	Maximum Frequency	External Feedback	1/(ts + tco)]	16		MHz
	(Note 2)	No Feedback	1/(tw+ + twL)		20		MHz
tezx	OE to Output Er	nable		1		25	ns
texz	OE to Output Di	sable		1	•	25	ns
tea	Input to Output Enable Using Product Term Control			16L8, 16R6,		35	ns
ter	Input to Output I	Disable Using Product Te	rm Control	16R4		35	ns

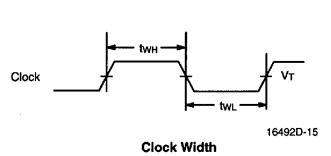
- 1. See Switching Test Circuit for test conditions.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.

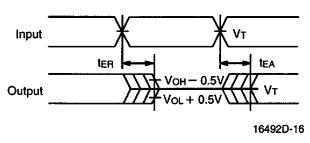
SWITCHING WAVEFORMS

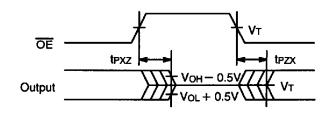












Input to Output Disable/Enable

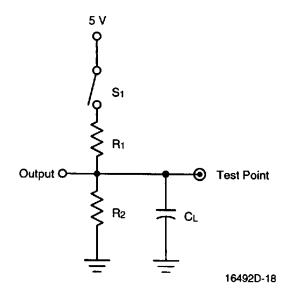
OE to Output Disable/Enable

- 1. $V_T = 1.5 V$
- 2. Input pulse amplitude 0 V to 3.0 V
- 3. Input rise and fall times 2 ns-3 ns typical.

KEY TO SWITCHING WAVEFORMS

WAVEFORM	INPUTS	OUTPUTS	
	Must be Steady	Will be Steady	
	May Change from H to L	Will be Changing from H to L	
	May Change from L to H	Will be Changing from L to H	
	Don't Care, Any Change Permitted	Changing, State Unknown	
>> ≪<	Does Not Apply	Center Line is High- Impedance "Off" State	
		KS000010-PAL	

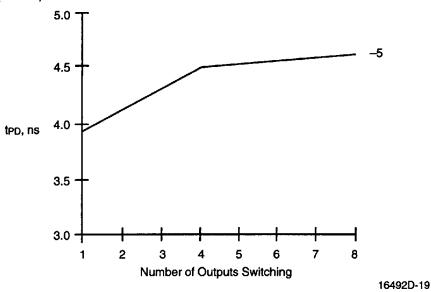
SWITCHING TEST CIRCUIT



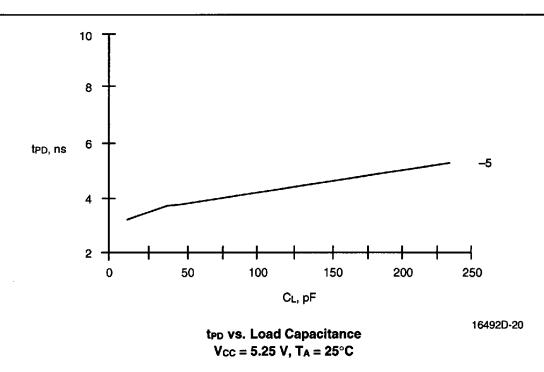
Specification	S ₁		Commercial		Measured
		CL	Ri	R ₂	Output Value
tpd, tco	Closed		All but B-4:	All but B-4:	1.5 V
tpzx, tea	$Z \rightarrow H$: Open $Z \rightarrow L$: Closed	50 pF	200 Ω	390 Ω	1.5 V
texz, ten	H → Z: Open L → Z: Closed	5 pF	B-4: 800 Ω	B-4: 1.56 kΩ	H → Z: VoH − 0.5 V L → Z: VoL + 0.5 V

MEASURED SWITCHING CHARACTERISTICS for the PAL16R8-5

 $V_{CC} = 4.75 \text{ V}, T_A = 75^{\circ}\text{C (Note 1)}$



tPD vs. Number of Outputs Switching



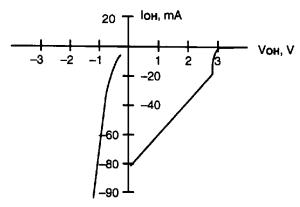
Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where tpp may be affected.

CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS for the PAL16R8-4/5 $V_{\rm CC}$ = 5.0 V, $T_{\rm A}$ = 25°C

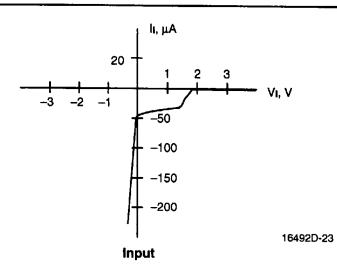
15 - loL, mA 10 - 5 - VoL, V -0.6 -0.4 -0.2 -5 -5 -10 -15 -15 -16492D-21

Output, LOW



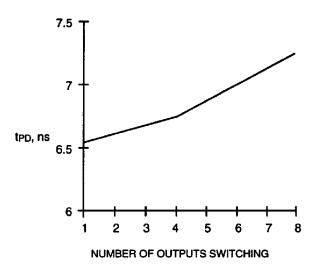
16492D-22

Output, HIGH



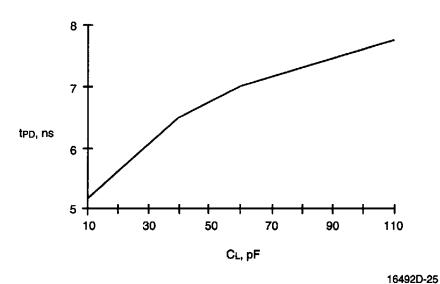
MEASURED SWITCHING CHARACTERISTICS for the PAL16R8-7

Vcc = 4.75 V, T_A = 75°C (Note 1)



tpp vs. Number of Outputs Switching

16492D-24

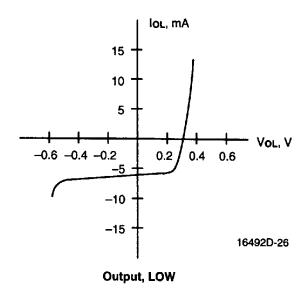


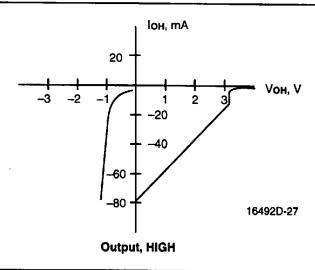
tpp vs. Load Capacitance

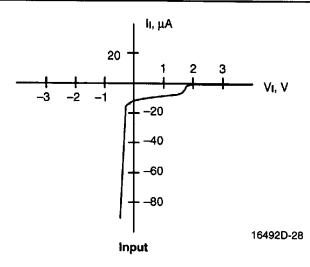
Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where tpp may be affected.

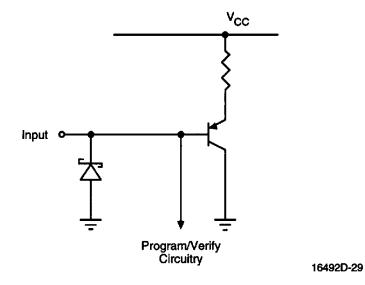
CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS for the PAL16R8-7 Vcc = 5.0 V, T_A = 25°C



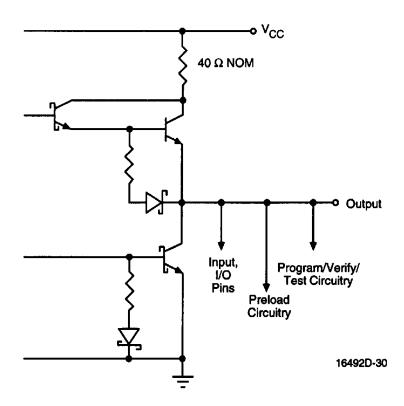




INPUT/OUTPUT EQUIVALENT SCHEMATICS



Typical Input



Typical Output

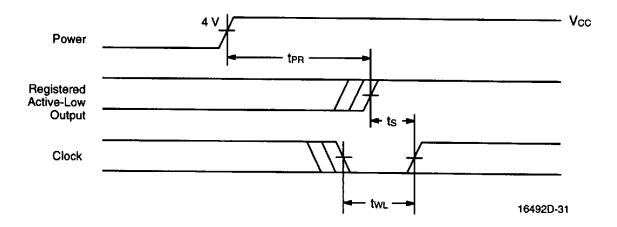


POWER-UP RESET

The power-up reset feature ensures that all flip-flops will be reset to LOW after the device has been powered up. The output state will be HIGH due to the inverting output buffer. This feature is valuable in simplifying state machine initialization. A timing diagram and parameter table are shown below. Due to the synchronous operation of the power-up reset and the wide range of ways Vcc can rise to its steady state, two conditions are required to ensure a valid power-up reset. These conditions are:

- The Vcc rise must be monotonic.
- Following reset, the clock input must not be driven from LOW to HIGH until all applicable input and feedback setup times are met.

Parameter Symbol	Parameter Description	Max	Unit		
t _{PR}	Power-Up Reset Time	1000	ns		
ts	Input or Feedback Setup Time	Son Custohian			
tw∟	Clock Width LOW		See Switching Characteristics		



Power-Up Reset Waveform